

TENTATIVE PROGRAM (as of 24/02/2021)

ZOOM Conferencing

Conference Time Zone – New York, USA (EST)

K: Keynote lecture / I: Invited Lecture / O: Oral / FP: FlashPoster



Tuesday (23/02/2021)

08:50 – 09:00: Opening - Welcome and Introduction

Antonio Correia (Phantoms foundation, Spain) / **James Hone** (Columbia University, USA) / **Mauricio Terrones** (PennState University, USA) / **Vincent Meunier** (Rennsselaer, USA) / **Luigi Colombo** (UTDallas, USA)

(PennState University, USA) / Vincent Meunier (Rennsselaer, USA) / Luigi Colombo (UTDallas, USA)	
09:00 – 09:30: Jun Lou (Rice University, USA)	K
Electrochemical Behaviors of Two-Dimensional Materials for Energy and Environmental Applications	I/
09:30 – 10:00: Francesco Bonaccorso (BeDimensional, Italy) Large-scale production of 2D crystals for energy applications	K
10:00 – 10:30: Richard Kaner (UCLA, USA)	K
Graphene Synthesis and Applications in Supercapacitors	K
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10:30– 11:00: Break / ePoster session / Exhibition	
PARALLEL SESSION 1	
11:00 – 11:20: Gordon Harling (CMC Microsystems, Canada)	I
Accessing Infrastructure for Prototyping and Measurement	
11:20 – 11:40: Gordon Rinke (AMO GmbH, Germany)	I
Wafer Scale Integration of Graphene - 2D Experimental Pilot Line at AMO	
11:40 – 12:00: Elías Torres Alonso (Graphenea, Spain)	I
Graphenea Foundry: a platform for the manufacture of graphene-based devices	_
12:00 – 12:10: Niels Wijnaendts van Resandt (Heidelberg Instruments, USA)	О
Direct Write Lithography Tools and Applications	
12:10 – 12:30: Mario Lanza (KAUST, Saudi Arabia)	I
Wafer-scale integration of two-dimensional materials in high-density memristive crossbar arrays for artificial neural networks	
12:30 – 12:50: An Chen (Semiconductor Research Corporation, USA)	ı
Nanoelectronics Research for Computing beyond CMOS	1
12:50 – 13:00: Mohamed Boukhicha (BNL, USA)	О
Large-scale Lithium-intercalated Multilayer Graphene Production	U
Edige Scale Edition interediated Matchayer Graphene Froduction	
PARALLEL SESSION 2	
11:00 – 11:20: Adina Luican-Mayer (University of Ottawa, Canada)	ı
Visualizing 2D materials at the atomic scale	
11:20 – 11:30: Andrey Krayev (HORIBA Scientific, USA)	0
Nanoscale Structural Peculiarities in Mono- to Few-Layer Crystals of Ti3C2Tx MXene Revealed by TERS.	
11:30 – 11:50: Sonia Conesa Boj (TU Delft, The netherlands)	1
From crafting to visualization: low-dimensional TMD nanostructures under the electron microscope lamppost	
11:50 – 12:10: Avik Ghosh (University of Virginia, USA)	I
Unconventional switching using topological properties of electrons in graphene based heterostructures	

12:10 – 12:30: Bruno Dlubak (CNRS/Thales, France) Spin filtering in graphene based magnetic tunnel junctions 12:30 – 12:50: Aida Ebrahimi (Pennsylvania State University, USA) All-Ink Dopamine Sensors with Ultralow Detection Limit Enabled by One-Step Annealing of Graphene Ink 12:50 – 13:00: Salvatore Polverino (Università degli studi di Genova, Italy) Few-layer graphene-based sustainable cement mortar	I I O
13:00 – 14:00: Lunch Break	
14:00 – 14:30: Dmitri Efetov (ICFO, Spain)	K
Competing phases of correlated Chern insulators in Superconducting Twisted Bilayer Graphene 14:30 – 15:00: Emanuel Tutuc (The University of Texas at Austin, USA)	K
Correlated Insulators and Topological Transport in Twisted Double Bilayer Graphene 15:00 – 15:30: Arend Van der Zande (University of Illinois, USA)	K
Electromechanical systems enabled by interfacial slip in 2D material heterostructures 15:30 – 16:00: Abhay Pasupathy (Columbia University, USA) Quantum phenomena in moire heterostructures	K
16:00 – 16:30: Break / ePoster session / Exhibition	
16:30 – 17:00: Matthew Yankowitz (University of Washington, USA)	K
Tunable correlated and topological states in twisted monolayer-bilayer graphene 17:00 – 17:10: Fida Ali (Sungkyunkwan University, South Korea)	0
Density of Interface States in Layered-WSe2 Semiconductor 17:10 – 17:20: Tien Dat Ngo (Sungkyunkwan University, South Korea)	0
Fermi-level de-pinning at the intrinsic WSe2-metal junction via van der Waals bottom contacts 17:20 – 17:30: Pawan Srivastava (Sungkyunkwan University, South Korea) Resonant tunneling through twisted black phosphorus homostructures	0
18:00 End of day 1	
18:00 End of day 1 Wednesday (24/02/2021)	
Wednesday (24/02/2021) 08:30 – 09:00: Robert Wallace (The University of Texas at Dallas, USA)	К
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Topological Spin Transport in Quantum Materials and Entanglement 13:10 – 13:20: Pablo Piskunow (Catalan Institute of Nanoscience and Nanotechnology, Spain) Hinge Spin Polarization in Magnetic Topological Insulators Revealed by Resistance Switch	0
13:20 – 14:00: Lunch Break	
14:00 – 14:10: Stephen Power (Trinity College Dublin, Ireland)	0
Manipulating valley currents in graphene nanostructures	
14:10 – 14:20: Megan Steves (The Pennsylvania State University, USA)	0
Correlating nonlinear optical properties with atomic-level structure in 2D-polar metals	
14:20 – 14:30: Andrea Tomadin (Università di Pisa, Italy)	0
Microscopic theory of plasmon-enabled resonant terahertz detection in bilayer graphene	
14:30 – 14:40: Raúl Guerrero (Centro de Física de Materiales, Spain)	0
Rhombohedral Phase in Trilayer-graphene	
14:40 – 15:10: Ado Jorio (Universidade Federal de Minas Gerais, Brazil)	K
Phonon localization in low-angle twisted bilayer graphene	
15:10 – 15:40: Jerzy Sadowski (Brookhaven National Laboratory, USA)	K
Interlayer coupling effects in the 30deg-twisted bilayer graphene	
15:40 – 16:40: Break / ePoster session / Exhibition	
16:40 – 17:10: Jamie Warner (University of Texas at Austin, USA)	K
Air Stable Noble Metal Dichalcogenide 2D layered Materials	
17:10 – 17:40: Rodney Ruoff (UNIST/CMCM, South Korea)	K
F-diamane from AB-stacked graphene	
17:40 – 18:10: Michael Fuhrer (Monash University, Australia)	K
2D Topological Insulators for Low-Energy Electronics	

18:10: Closing